

8-CHANNEL ANALOG MULTIPLEXER/DEMULPLEXER

FEATURES

- Wide analog input voltage range: ± 5 V.
- Low "ON" resistance:
80 Ω (typ.) at $V_{CC} - V_{EE} = 4.5$ V
70 Ω (typ.) at $V_{CC} - V_{EE} = 6.0$ V
60 Ω (typ.) at $V_{CC} - V_{EE} = 9.0$ V
- Logic level translation:
to enable 5 V logic to communicate
with ± 5 V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- I^{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT4051 are high-speed Si-gate CMOS devices and are pin compatible with the "4051" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4051 are 8-channel analog multiplexers/demultiplexers with three digital select inputs (S_0 to S_2), an active LOW enable input ($\bar{E}$), eight independent inputs/outputs (Y_0 to Y_7) and a common input/output (Z).

With $\bar{E}$ LOW, one of the eight switches is selected (low impedance ON-state) by S_0 to S_2 . With $\bar{E}$ HIGH, all switches are in the high impedance OFF-state, independent of S_0 to S_2 .

V_{CC} and GND are the supply voltage pins for the digital control inputs (S_0 to S_2 , and $\bar{E}$). The V_{CC} to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT. The analog inputs/outputs (Y_0 to Y_7 , and Z) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit. $V_{CC} - V_{EE}$ may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to GND (typically ground).

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PZH}/t_{PZL}	turn "ON" time $\bar{E}$ to V_{OS} S_n to V_{OS}	$C_L = 15$ pF $R_L = 1$ k Ω $V_{CC} = 5$ V	22 20	22 24	ns ns
t_{PHZ}/t_{PLZ}	turn "OFF" time $\bar{E}$ to V_{OS} S_n to V_{OS}		18 19	16 20	ns ns
C_i	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per switch	notes 1 and 2	25	25	pF
C_S	max. switch capacitance independent (Y) common (Z)		5 25	5 25	pF pF

$V_{EE} = \text{GND} = 0$ V; $T_{amb} = 25^\circ\text{C}$; $t_r = t_f = 6$ ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\} \text{ where:}$$

f_i = input frequency in MHz

f_o = output frequency in MHz

$\sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$ = sum of outputs

C_L = output load capacitance in pF

C_S = max. switch capacitance in pF

V_{CC} = supply voltage in V

2. For HC the condition is $V_I = \text{GND}$ to V_{CC}

For HCT the condition is $V_I = \text{GND}$ to $V_{CC} - 1.5$ V

PACKAGE OUTLINES

16-lead DIL; plastic (SOT38Z).

16-lead mini-pack; plastic (SO16; SOT109A).

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
3	Z	common input/output
6	$\bar{E}$	enable input (active LOW)
7	V_{EE}	negative supply voltage
8	GND	ground (0 V)
11, 10, 9	S_0 to S_2	select inputs
13, 14, 15, 12, 1, 5, 2, 4	Y_0 to Y_7	independent inputs/outputs
16	V_{CC}	positive supply voltage

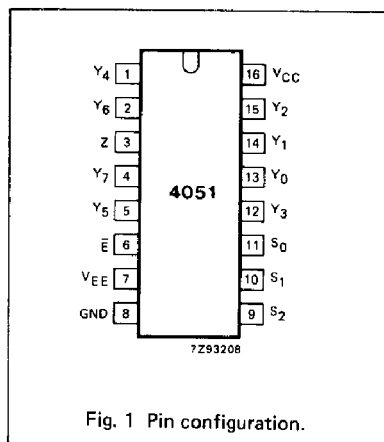


Fig. 1 Pin configuration.

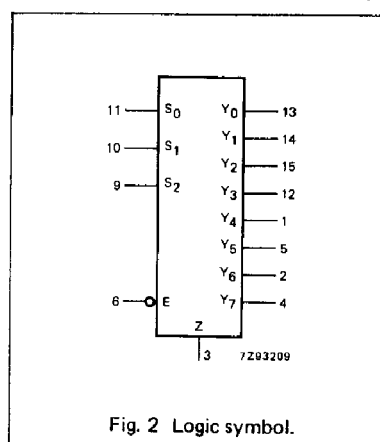


Fig. 2 Logic symbol.

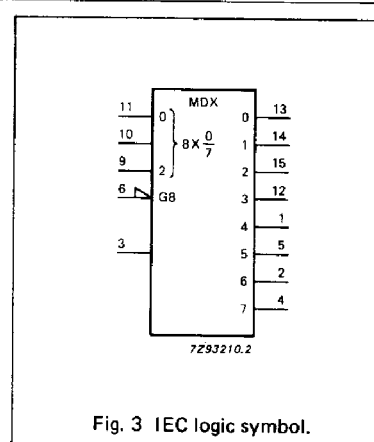
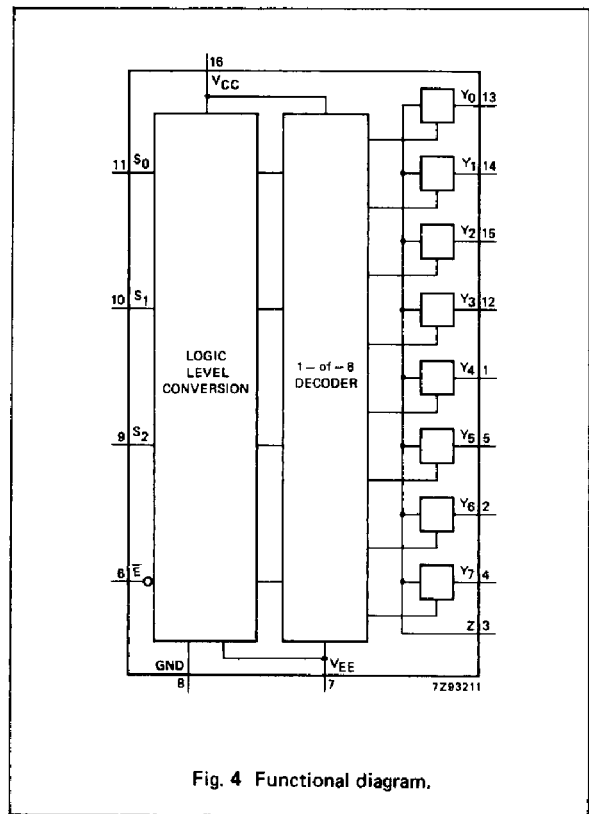


Fig. 3 IEC logic symbol.



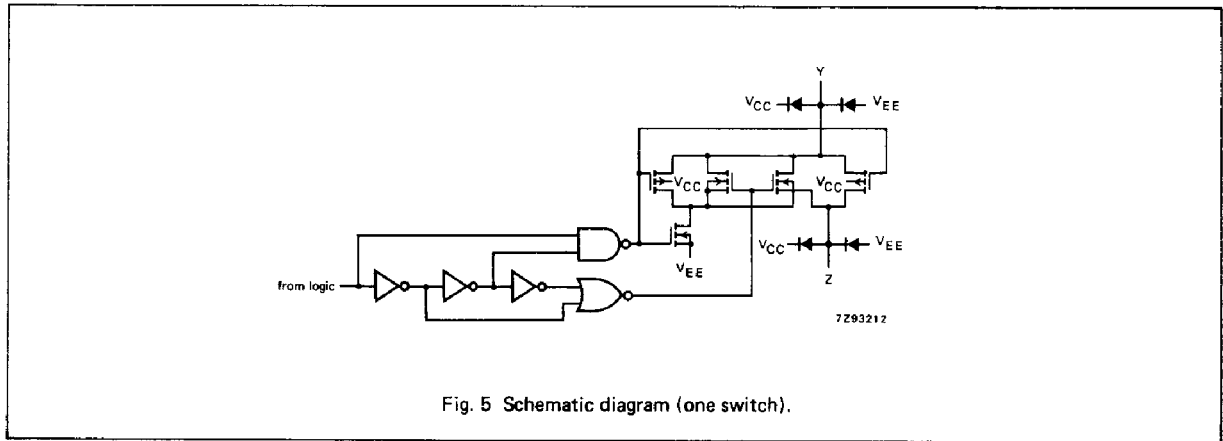
APPLICATIONS

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

FUNCTION TABLE

INPUTS				channel ON
$\bar{E}$	S_2	S_1	S_0	
L	L	L	L	$Y_0 - Z$
L	L	L	H	$Y_1 - Z$
L	L	H	L	$Y_2 - Z$
L	L	H	H	$Y_3 - Z$
L	H	L	L	$Y_4 - Z$
L	H	L	H	$Y_5 - Z$
L	H	H	L	$Y_6 - Z$
L	H	H	H	$Y_7 - Z$
H	X	X	X	none

H = HIGH voltage level
L = LOW voltage level
X = don't care



RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to $V_{EE} = \text{GND}$ (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
V_{CC}	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5 \text{ V}$ or $V_S > V_{CC} + 0.5 \text{ V}$
$\pm I_S$	DC switch current		25	mA	for $-0.5 \text{ V} < V_S < V_{CC} + 0.5 \text{ V}$
$\pm I_{EE}$	DC V_{EE} current		20	mA	
$\pm I_{CC};$ $\pm I_{GND}$	DC V_{CC} or GND current		50	mA	
T_{stg}	storage temperature range	-65	+150	°C	
P_{tot}	power dissipation per package				for temperature range: -40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K
P_S	power dissipation per switch		100	mW	

Note to ratings

To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Y_n , the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{CC} current will flow out of terminals Y_n . In this case there is no limit for the voltage drop across the switch, but the voltages at Y_n and Z may not exceed V_{CC} or V_{EE} .

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
V_{CC}	DC supply voltage $V_{CC}-\text{GND}$	2.0	5.0	10.0	4.5	5.0	5.5	V	see Figs 6 and 7
V_{CC}	DC supply voltage $V_{CC}-V_{EE}$	2.0	5.0	10.0	2.0	5.0	10.0	V	see Figs 6 and 7
V_I	DC input voltage range	GND		V_{CC}	GND		V_{CC}	V	
V_S	DC switch voltage range	V_{EE}		V_{CC}	V_{EE}		V_{CC}	V	
T_{amb}	operating ambient temperature range	-40		+85	-40		+85	°C	see DC and AC CHARACTERISTICS
T_{amb}	operating ambient temperature range	-40		+125	-40		+125	°C	
t_r, t_f	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ $V_{CC} = 10.0 \text{ V}$

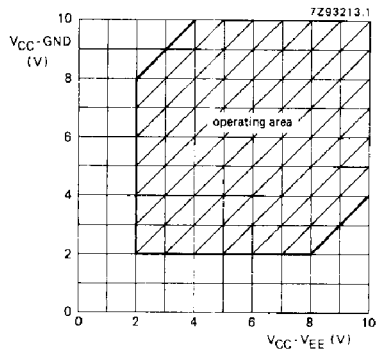


Fig. 6 Guaranteed operating area as a function of the supply voltages for 74HC4051.

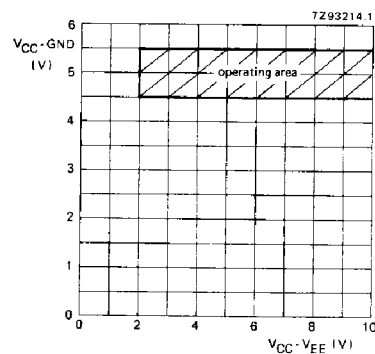


Fig. 7 Guaranteed operating area as a function of the supply voltages for 74HCT4051.

DC CHARACTERISTICS FOR 74HC/HCT

For 74HC: $V_{CC} - GND$ or $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$ and 9.0 V

For 74HCT: $V_{CC} - GND = 4.5$ and 5.5 V; $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$ and 9.0 V

SYMBOL	PARAMETER	T _{amb} (°C)								UNIT	TEST CONDITIONS				
		74HC/HCT									V _{CC} V	V _{EE} V	I _S μA	V _{is}	V _I
		+25			-40 to +85		-40 to +125								
		min.	typ.	max.	min.	max.	min.	max.							
R _{ON}	ON resistance (peak)		—	—		—		—	Ω	2.0	0	100	V _{CC} or V _{EE}	V _{IH} or V _L	
			100	180		225		270	Ω	4.5	0	1000			
			90	160		200		240	Ω	6.0	0	1000			
			70	130		165		195	Ω	4.5	-4.5	1000			
R _{ON}	ON resistance (rail)		150	—		—		—	Ω	2.0	0	100	V _{EE}	V _{IH} or V _L	
			80	140		175		210	Ω	4.5	0	1000			
			70	120		150		180	Ω	6.0	0	1000			
			60	105		130		160	Ω	4.5	-4.5	1000			
R _{ON}	ON resistance (rail)		150	—		—		—	Ω	2.0	0	100	V _{CC}	V _{IH} or V _L	
			90	160		200		240	Ω	4.5	0	1000			
			80	140		175		210	Ω	6.0	0	1000			
			65	120		150		180	Ω	4.5	-4.5	1000			
ΔR _{ON}	maximum ΔON resistance between any two channels		—						Ω	2.0	0		V _{CC} to V _{EE}	V _{IH} or V _L	
			9						Ω	4.5	0				
			8						Ω	6.0	0				
			6						Ω	4.5	-4.5				

Notes to DC characteristics

- At supply voltages ($V_{CC} - V_{EE}$) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring R_{ON} see Fig. 8.

DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T _{amb} (°C)								UNIT	TEST CONDITIONS			
		74HC									V _{CC} V	V _{EE} V	V _I	OTHER
		+25			-40 to +85		-40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
V _{IH}	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.7		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3		V	2.0 4.5 6.0 9.0				
V _{IL}	LOW level input voltage		0.8 2.1 2.8 4.3	0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7	V	2.0 4.5 6.0 9.0				
±I _I	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	0 0	V _{CC} or GND		
±I _S	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} - V _{EE} (see Fig. 10)	
±I _S	analog switch OFF-state current all channels			0.4		4.0		4.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} - V _{EE} (see Fig. 10)	
±I _S	analog switch ON-state current			0.4		4.0		4.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} - V _{EE} (see Fig. 11)	
I _{CC}	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	6.0 10.0	0 0	V _{CC} or GND	V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}	

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS		
		74HC								V _{CC} V	V _{EE} V	OTHER
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t _{PHL} / t _{PLH}	propagation delay V _{is} to V _{os}		14 5 4 4	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R _L = ∞; C _L = 50 pF (see Fig. 17)
t _{PZH} / t _{PZL}	turn "ON" time E to V _{os}		72 29 21 18	345 69 59 51		430 86 73 64		520 104 88 77	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)
t _{PZH} / t _{PZL}	turn "ON" time S _n to V _{os}		66 28 19 16	345 69 59 51		430 86 73 64		520 104 88 77	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)
t _{PHZ} / t _{PLZ}	turn "OFF" time E to V _{os}		58 31 17 18	290 58 49 42		365 73 62 53		435 87 74 72	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)
t _{PHZ} / t _{PLZ}	turn "OFF" time S _n to V _{os}		61 25 18 18	290 58 49 42		365 73 62 53		435 87 74 72	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)

DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0)

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS			
		74HCT								V _{CC} V	V _{EE} V	V _I	OTHER
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
V _{IH}	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5			
V _{IL}	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5			
±I _I	input leakage current			0.1		1.0		1.0	μA	5.5	0	V _{CC} or GND	
±I _S	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} - V _{EE} (see Fig. 10)
±I _S	analog switch OFF-state current all channels			0.4		4.0		4.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} - V _{EE} (see Fig. 10)
±I _S	analog switch ON-state current			0.4		4.0		4.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} - V _{EE} (see Fig. 11)
I _{CC}	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	5.5 5.0	0 -5.0	V _{CC} or GND	V _{IS} = V _{EE} or V _{CC} ; V _{OS} = V _{CC} or V _{EE}
ΔI _{CC}	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	0	V _{CC} - 2.1V	other inputs at V _{CC} or GND

Note to HCT types

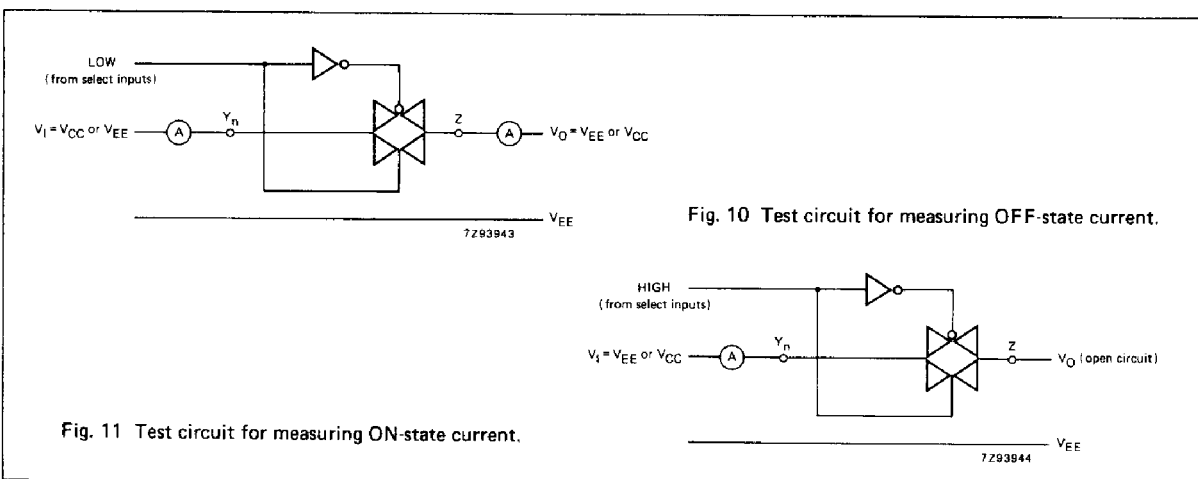
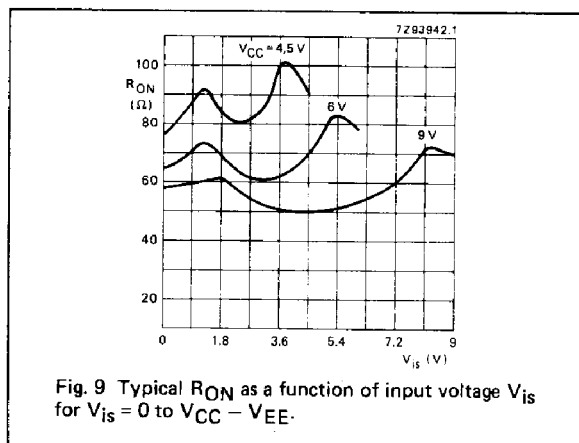
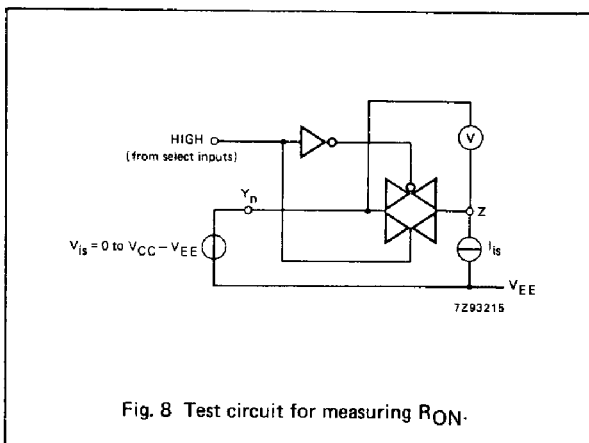
1. The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given here.
To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
S _n	0.50
E	0.50

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS		
		74HCT								V _{CC} V	V _{EE} V	OTHER
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t _{PHL} / t _{PLH}	propagation delay V _{is} to V _{os}		5 4	12 8		15 10		18 12	ns	4.5 4.5	0 -4.5	R _L = ∞; C _L = 50 pF (see Fig. 17)
t _{PZH} / t _{PZL}	turn "ON" time E to V _{os}		26 16	55 39		69 49		83 59	ns	4.5 4.5	0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)
t _{PZH} / t _{PZL}	turn "ON" time S _N to V _{os}		28 16	55 39		69 49		83 59	ns	4.5 4.5	0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)
t _{PHZ} / t _{PLZ}	turn "OFF" time E to V _{os}		19 16	45 32		56 40		68 48	ns	4.5 4.5	0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)
t _{PHZ} / t _{PLZ}	turn "OFF" time S _N to V _{os}		23 16	45 32		56 40		68 48	ns	4.5 4.5	0 -4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 18, 19 and 20)



ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values

GND = 0 V; $T_{amb} = 25^\circ\text{C}$

SYMBOL	PARAMETER	typ.	UNIT	V_{CC} V	V_{EE} V	$V_{is(p-p)}$ V	CONDITIONS
	sine-wave distortion $f = 1\text{ kHz}$	0.04 0.02	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	$R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$ (see Fig. 14)
	sine-wave distortion $f = 10\text{ kHz}$	0.12 0.06	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	$R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$ (see Fig. 14)
	switch "OFF" signal feed-through	-50 -50	dB dB	2.25 4.5	-2.25 -4.5	note 1	$R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$ (see Figs 12 and 15)
$V_{(p-p)}$	crosstalk voltage between control and any switch (peak-to-peak value)	110 220	mV mV	4.5 4.5	0 -4.5		$R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $f = 1\text{ MHz}$ (E or S_n , square-wave between V_{CC} and GND, $t_r = t_f = 6\text{ ns}$) (see Fig. 16)
f_{max}	minimum frequency response (-3dB)	170 180	MHz MHz	2.25 4.5	-2.25 -4.5	note 2	$R_L = 50\text{ }\Omega$; $C_L = 10\text{ pF}$ (see Figs 13 and 14)
C_S	maximum switch capacitance independent (Y) common (Z)	5 25	pF pF				

Notes to AC characteristics

General note

 V_{is} is the input voltage at a Y_n or Z terminal, whichever is assigned as an input. V_{os} is the output voltage at a Y_n or Z terminal, whichever is assigned as an output.

Notes

1. Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

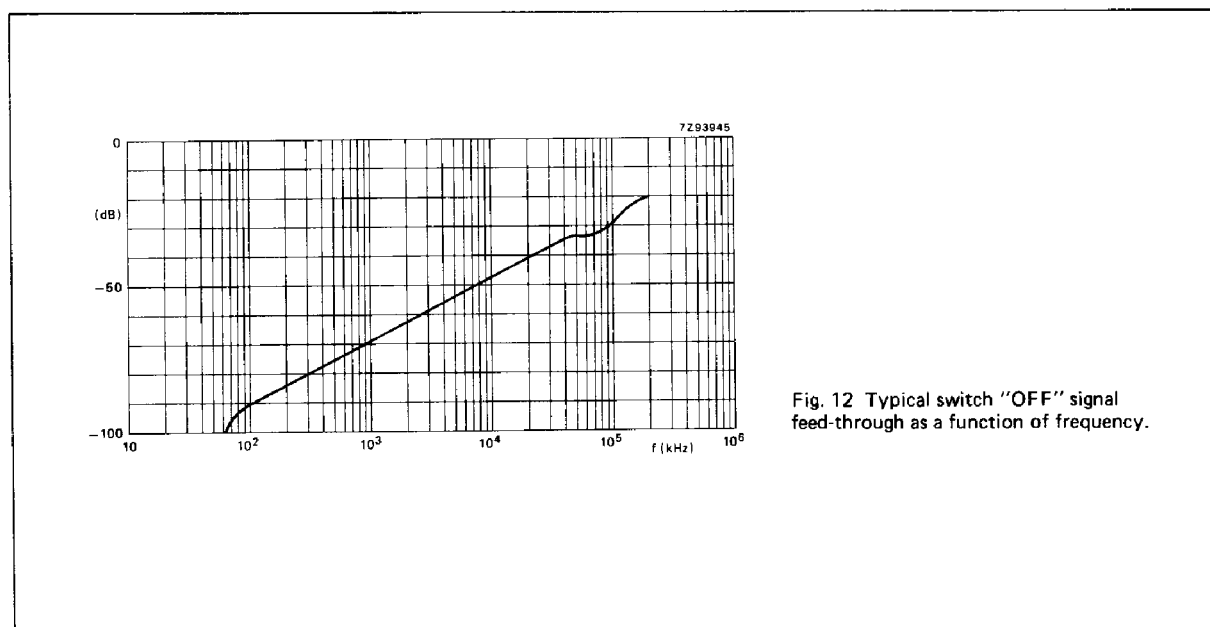
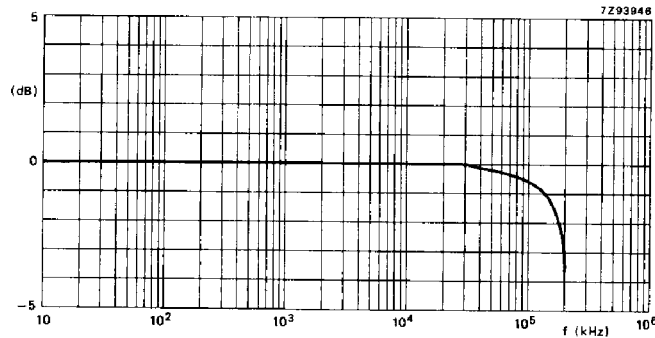


Fig. 12 Typical switch "OFF" signal feed-through as a function of frequency.



Note to Figs 12 and 13

Test conditions:
 $V_{CC} = 4.5 \text{ V}$; $GND = 0 \text{ V}$; $V_{EE} = -4.5 \text{ V}$;
 $R_L = 50 \Omega$; $R_{source} = 1 \text{ k}\Omega$

Fig. 13 Typical frequency response.

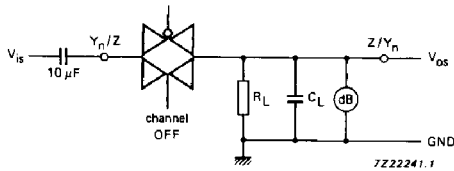


Fig. 14 Test circuit for measuring sine-wave distortion and minimum frequency response.

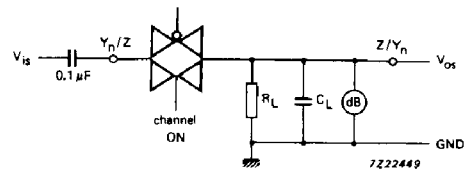


Fig. 15 Test circuit for measuring switch "OFF" signal feed-through.

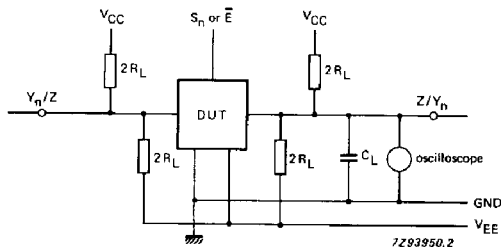
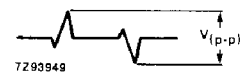


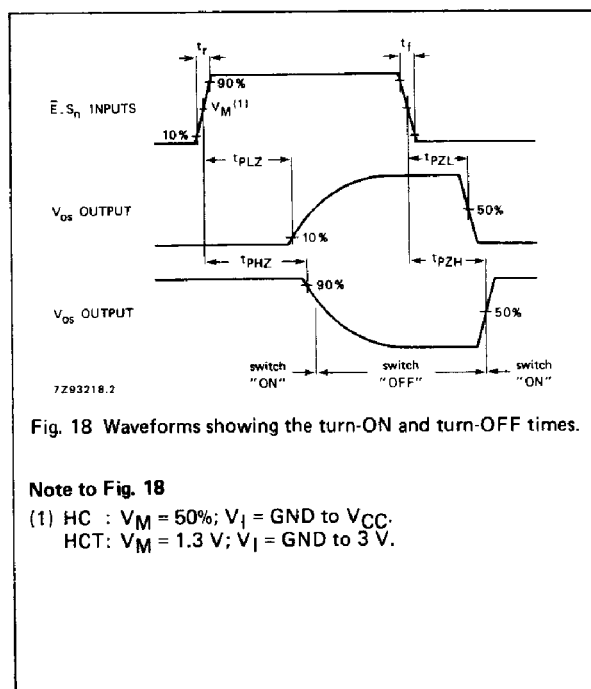
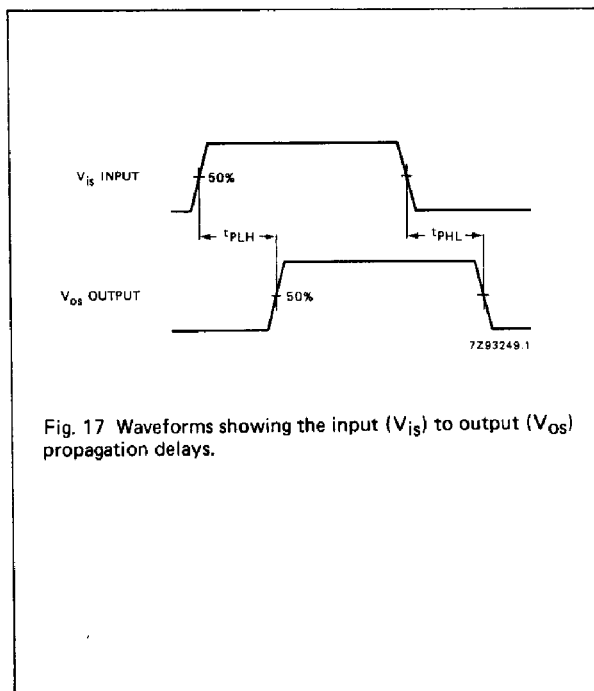
Fig. 16 Test circuit for measuring crosstalk between control and any switch.

Note to Fig. 16

The crosstalk is defined as follows (oscilloscope output):



AC WAVEFORMS



Note to Fig. 18

(1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$
HCT: $V_M = 1.3 \text{ V}$; $V_I = \text{GND to } 3 \text{ V}$.

TEST CIRCUIT AND WAVEFORMS

